| Model Parameter Descriptions and Default Values |  |  |                                  |
|---|--|--|----------------------------------|
| Parameters                                      | Descriptions   | Default Value                                    | Suggested Range <sup>1</sup>     |
| а   | Lattice oxygen distance  | 0.5 nm   | [0.3,1]                          |
| f   | O <sup>2-</sup> vibration frequency                              | $10^{13}\mathrm{Hz}$                             | $[10^{12}, 10^{14}]$             |
| $E_a$   | Activation energy of O <sup>2-</sup>                             | 1.0 eV   | [0.8,1.5]                        |
| $E_r$   | Recombination barrier between V <sub>O</sub> and O <sup>2-</sup> | 1.25 eV  | [0.8,1.5]                        |
| $E_o$   | Kinetic barrier of O <sup>2-</sup> from IML to RS region         | 1.0 eV   | [0.8,1.5]                        |
| $E_{AC}$  | Activation energy of conductance in VR region                    | -0.001 eV  | [-0.01,0]                        |
| $\Psi_{1}$                                      | Energy barrier between RS layer and BE                           | 1.55 V   | [0.5,2]                          |
| $\Psi_2$  | Energy barrier between IML and RS layer                          | 0.85 V   | [0.5,2]                          |
| $lpha_1$  | Field enhancement factor for SET                                 | 0.95   | [0.5,1.5]                        |
| $lpha_2$  | Field enhancement factor for RESET                               | 1.2  | [0.5,1.5]                        |
| Z & e   | Charge number & unit charge                                      | 2 & e  | 2 & e                            |
| $R_{th}$  | Effective thermal resistance                                     | $1.8 \times 10^6 \text{ K/W}$                    | $[1 \times 10^6, 5 \times 10^6]$ |
| $L_{IML}$                                       | Intermediate modulation layer thickness                          | 60 nm  | [0,100]                          |
| $L_{VR}$  | VR region height   | 5.5nm  | [0,10]                           |
| $L_{RS}$  | RS region height   | 2.5 nm   | [0,10]                           |
| $W_{IML}$                                       | Intermediate modulation layer width                              | 30 nm  | [0,100]                          |
| $w_0$   | Conductance filament redius                                      | 2.5nm  | [0,5]                            |
| $\boldsymbol{A}$                                | (The coefficient associated with the relationship                | 1.5×10 <sup>-6</sup>                             | 1.5×10 <sup>-6</sup>             |
| B   | between conductance and electric field)                          | $1 \times 10^{9}$                                | 1×10 <sup>9</sup>                |
| $C_{V0}$  | The proportion of Vo in lattice oxygen                           | 0.9  | [0,1]                            |
| $C_{OO}$  | The proportion of O <sup>2-</sup> in lattice oxygen              | 0  | [0,1]                            |
| $\sigma_{v0}$                                   | Initial conductivity of VR region                                | $3\times10^4~\Omega^{-1}~{\rm m}^{-1}$           | ~10 <sup>4</sup>                 |
| $\sigma_{IML}$                                  | Initial conductivity of IML region                               | $1.25 \times 10^5 \ \Omega^{-1} \ \text{m}^{-1}$ | $[10^3, 10^6]$                   |

<sup>&</sup>lt;sup>1</sup> The range listed represents reasonable values based on experimental observations and physical insights. The units should be the same as the default values.